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Design and construction of the sandwich-like Z-scheme multicomponent CdS/Ag/Bi₂MoO₆ heterostructure with enhanced photocatalytic performance in RhB photodegradation†

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A sandwich-like Z-scheme tricomponent CdS/Ag/Bi₂MoO₆ photocatalytic system was rationally designed and successfully fabricated, in which Ag was loaded onto Bi₂MoO₆ microspheres by a facile photoreduction method and CdS was subsequently deposited onto the surface of Bi₂MoO₆ and Ag/Bi₂MoO₆ through a deposition–precipitation method. During this process, a series of Ag/Bi₂MoO₆ and CdS/Bi₂MoO₆ were also prepared. All the composites were characterized by XRD, TEM, SEM, EDX, XPS, UV-vis DRS, and IR spectra to confirm the successful integration of Ag or (and) CdS with Bi₂MoO₆, the alteration of morphology and the formation of a new phase before and after Ag or (and) CdS loading. The degradation of rhodamine B (RhB) dye under visible light irradiation (>420 nm) revealed that the CdS/Ag/Bi₂MoO₆ composite exhibited a highly visible-light-responsive photocatalytic performance compared to single Bi₂MoO₆ or CdS and dual Ag/Bi₂MoO₆ or CdS/Bi₂MoO₆. The enhanced photocatalytic performance of CdS/Ag/Bi₂MoO₆ was ascribed to its special structure – a typical Z-scheme photocatalytic system, in which Ag nanoparticles directly connected to the surface of CdS and Bi₂MoO₆ to form a solid–solid interface (ohmic contact), acting as a conductor that greatly shortened the distance for photogenerated electron transfer and combined photogenerated electrons from the CB of Bi₂MoO₆ with the photogenerated holes from the VB of CdS through ohmic contact, and thereby led to the efficient separation of photogenerated electrons and holes and showed stable and strong reducibility and oxidizability. Moreover, the surface plasmon resonance effect of metallic Ag nanoparticles also played an important role in the enhanced photocatalytic performance of RhB degradation under visible light irradiation. Furthermore, investigations on photoluminescence and photoelectrochemical properties also demonstrated indirectly the highly efficient separation of photogenerated electrons and holes in the Z-scheme CdS/Ag/Bi₂MoO₆ photocatalytic system. This new Z-scheme photocatalytic system will be applied to more photoreactions in further exploration.

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1 Introduction

Semiconductor-based photocatalysis has attracted considerable attention as it is a promising pathway for solving increasingly serious energy and environmental problems.¹ In these photocatalytic reactions, TiO₂ is a typical photocatalyst that is widely used in H₂ or O₂ production and the degradation of organic pollutants.^{2–4} Unfortunately, TiO₂ as a photocatalyst shows two

main drawbacks: (i) a wide band gap of 3.2 eV, which can be photoactivated under UV light to exhibit low solar energy conversion efficiency;^{5–7} (ii) the high recombination of photo-generated electron–hole pairs in the TiO₂ system leads to low quantum efficiency.⁸ These shortcomings greatly limit its practical applications. Therefore, the development of highly efficient, sustainable and visible-light-responsive photocatalytic materials is essential.

Bismuth molybdate (Bi₂MoO₆), featuring a layered configuration, is the simplest member of the Aurivillius family of layered perovskites, and consists of [Bi₂O₂]²⁺ layers interleaved with perovskite-like [MoO₄]²⁻ layers,^{9,10} displaying an excellent photocatalytic performance for completely degrading organic pollutants in waste water under visible light irradiation.^{10–13} Bi₂MoO₆ as a semiconductor has a smaller band gap, ranging from 2.5 to 2.8 eV, and is capable of capturing visible light.¹⁴ Owing to the low visible light utilization efficiency and the high

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recombination of photo-induced electrons and holes, the practical application of individual-phase Bi_2MoO_6 was limited.^{13,15,16} To overcome the intrinsic limitations of the single-component Bi_2MoO_6 , heterojunctioned or multi-component Bi_2MoO_6 -based photocatalysts have been prepared to improve/enhance their properties in repressing the recombination of photogenerated electron-hole pairs through an efficient charge transfer process and thereby drive efficient photo-reduction and oxidation reactions at spatially separated sites.^{14,17–20} Hence, the integration of a heterocomposite into single-component Bi_2MoO_6 to prepare Bi_2MoO_6 -based multi-composites is becoming a pivotal strategy for improving their photocatalytic performance in practical applications. CdS is an important II–VI semiconductive metal chalcogenide material, that is regarded as a very promising class of visible-light-driven photocatalysts, due to its wide light response (up to 520 nm or even longer).^{21–23} But, the application of pure CdS is encountering an enormous challenge – the easy aggregation of small-sized single CdS particles and its instability in air,^{24,25} due to easy oxidation of S^{2-} in CdS. Note that CdS attached on the surface of a (non)metal-based composite formed heterojunction nanocomposites ($\text{CdS}@g\text{-C}_3\text{N}_4$ and $\text{CdS}/\text{Bi}_2\text{MoO}_6$), efficiently showing an enhanced visible light photocatalytic activity and photostability compared to pure CdS.^{26–28} The improvement of the photocatalytic efficiency of photocatalysts is achieved by promoting the fast effective separation of photogenerated electrons and holes (impeding the recombination of electrons and holes as much as possible). In fact, photocatalysis is a light-driven chemical process occurring over the surface of a photocatalyst,²⁹ or is the acceleration of a photoinduced chemical reaction in the presence of catalyst, and a photoinduction reaction is activated by absorption of a photon with sufficient energy³⁰ – water can produce hydrogen,^{31–33} solar energy can convert into electrical energy,^{34,35} CO_2 can be reduced to organic fuels,^{36–38} and organic pollutants can be degraded.^{39–41} The absorption leads to a charge separation – the formation of negative electrons in the conduction band and positive holes in the valence band of the semiconductor catalyst. It is known that the electrons in the less negative conduction band (CB) and holes in the less positive valence band (VB) show weak redox ability.²⁰ Consequently, a typical semiconductor heterojunction displays a fatal shortcoming – the reduced redox ability of transferred electrons and holes, which negatively affect the photocatalytic reactions.⁴² Thus, it is an enormous challenge to establish a photocatalytic system with both fast electron-hole separation and strong redox ability. Hence, the single-component photocatalyst cannot easily simultaneously satisfy all the strict requirements – “a wide absorption range, long-term stability, high charge-separation efficiency and strong redox ability”; multicomposite photocatalytic systems are becoming more and more important, especially, the all-solid-state Z-scheme photocatalytic systems. In 2006, an all-solid-state photosystem-conductor-photosystem (PS–C–PS) system – a so-called Z-scheme CdS-Au-TiO_2 system – was reported for the first time, in which PSI(CdS), PSII(TiO_2) and the electron-transfer system (Au) were spatially fixed.⁴³ Since then, the artificial heterogeneous all-solid-state Z-scheme photocatalytic system has been widely investigated.²⁹ Especially note

that the photogenerated electrons and holes are respectively left in the CB of photosystem I and the VB of photosystem II, thereby achieving the efficient separation of electrons and holes. This process markedly differs from the conductor heterojunction-type charge-transfer mechanism. Such a Z-scheme pathway of electron transfer can preserve the oxidative holes in the lower VB and reductive electrons in the higher CB, resulting in not only a great improvement in separation efficiency, but also the strong reducibility of photogenerated electrons from photosystem I and the strong oxidizability of holes from photosystem II.^{20,29} Up to now, several Z-scheme photocatalytic systems containing silver have been successfully designed and constructed for the photocatalytic conversion of solar energy and the photocatalytic degradation of pollutants in waste water.^{20,29,44–56}

Nevertheless, in a semiconductor heterojunction, the Z-scheme charge transfer process usually faces competition from the typical charge transfer process.²⁹ A conductor or a contact interface with low contact resistance can be applied as an electron mediator to speed up the desirable specific carrier transfer.^{43,45,52,56–58} For example, Ag has an excellent electron conductivity and has often been used as a mediator in many Z-scheme systems.^{20,45–56} Moreover, Ag nanoparticles with localized surface plasmon resonance (SPR) properties have strong absorption under visible light.^{59,60} On the basis of these advantages, Ag particles as conductors have attracted considerable attention.^{20,45,47–57,61}

In this study, we rationally designed and successfully fabricated an all-solid-state Z-scheme $\text{CdS-Ag-Bi}_2\text{MoO}_6$ photocatalytic system, including CdS and Bi_2MoO_6 as the visible-light active photocatalysts and Ag as a solid electron mediator, and showed an enhanced photocatalytic performance for degrading organic pollutants, compared with single-component Bi_2MoO_6 , dual $\text{Ag}/\text{Bi}_2\text{MoO}_6$, and $\text{CdS}/\text{Bi}_2\text{MoO}_6$. The enhanced performance of the $\text{CdS}/\text{Ag}/\text{Bi}_2\text{MoO}_6$ was ascribed to the separation efficiency of photoinduced carriers and the strong reducibility and oxidizability of the photogenerated electrons and holes. A Z-scheme charge-transfer mechanism for efficient separation of photogenerated electrons and holes was suggested to elucidate photocatalytic reactions over the $\text{CdS}/\text{Ag}/\text{Bi}_2\text{MoO}_6$ photocatalyst, according to data obtained by photoluminescence (PL) spectra, photocurrent generation, and electrochemical impedance spectroscopy (EIS). Hence, the combination of all the advantages of the visible-light-responsive Ag, Bi_2MoO_6 and CdS photocatalysts in the $\text{CdS-Ag-Bi}_2\text{MoO}_6$ system might be a promising strategy for achieving highly efficient separation of electrons and holes and performing rapid photodegradation of organic pollutants, such as rhodamine B and methyl orange.

2 Experimental

2.1 Sample preparation

2.1.1 Preparation of Bi_2MoO_6 . All the chemicals were analytical grade and used as received. Distilled water was used in all experiments. Bi_2MoO_6 microspheres were prepared according to slightly modified literature procedures.¹⁹ In a typical process,



a certain stoichiometric amount of $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$ was dissolved in 13.0 mL of ethylene glycol (EG) under vigorous stirring, and 0.65 mmol of $\text{Na}_2\text{MoO}_4 \cdot 2\text{H}_2\text{O}$ powder was then added and continuously stirred for 30 min until a transparent solution was formed. Afterwards, 32.5 mL of ethanol was added and the mixture was stirred for another 30 min. Finally, the miscible solution was transferred into a 65.0 mL Teflon-lined stainless steel autoclave. The autoclave was sealed and maintained at 160 °C for 12 h, and then naturally cooled to room temperature. The resulting precipitates were separated by centrifugation and washed with deionized water several times, then dried at 60 °C for 12 h in a vacuum oven.

2.1.2 Synthesis of Ag/Bi₂MoO₆ photocatalysts. Silver nanoparticles deposited on the surface of Bi₂MoO₆ were prepared by a photoreduction process according to our previous work.⁶² To an aqueous suspension of Bi₂MoO₆ (1.0 mmol), an appropriate amount of AgNO₃ solution (18 mL, 10⁻⁴ g mL⁻¹) was added under stirring. Then, the suspension was irradiated at ambient temperature for 3 h using a 400 W xenon lamp under stirring. During the irradiation, the supernatant was collected and tested until Ag⁺ was precipitated completely. After the photoreduction process was completed, the Ag-loaded Bi₂MoO₆ was filtered and washed with water to completely remove NO₃⁻ ions, then dried at 60 °C for 12 h in a vacuum oven. The theoretically deposited amount of Ag is 1.0 at% to Bi₂MoO₆, and the resultant sample, Ag/Bi₂MoO₆, was denoted as A/BMO.

2.1.3 Fabrication of CdS/Ag/Bi₂MoO₆ photocatalyst. All the CdS/Ag/Bi₂MoO₆ photocatalysts were fabricated *via* a deposition-precipitation method. A detailed procedure is as follows: the obtained Ag/Bi₂MoO₆ (0.6099 g) was dispersed in 25 mL of absolute ethanol solution for 1 h under stirring, and appropriate amounts of Cd(CH₃COO)₂ · 2H₂O were then added. After being stirred at ambient temperature for 2 h, equimolar thioacetamide (TAA) ethanol solution (0.133 M) was added to the above suspension and stirred at room temperature for another 1 h. The suspension was sealed in a Teflon-lined stainless steel vessel and heated at 180 °C for 10 h. After cooling to room temperature, the as-prepared product was centrifugally separated and washed with water and absolute ethanol several times. Finally, the as-made sample was dried at 60 °C in a vacuum oven to obtain CdS/Ag/Bi₂MoO₆ (C/A/BMO). The CdS/Ag/Bi₂MoO₆ composites with molar ratios of CdS to Ag/Bi₂MoO₆ of 80, 100, 120, 140, and 160% were marked as 80 at% C/A/BMO, 100 at% C/A/BMO, 120 at% C/A/BMO, 140 at% C/A/BMO, and 160 at% C/A/BMO, respectively. The same procedure was used to prepare 120 at% CdS/Bi₂MoO₆ by depositing CdS on the surface of pure Bi₂MoO₆, and the obtained product was marked as 120 at% C/BMO. For comparison, single CdS was prepared *via* a similar procedure in the absence of Bi₂MoO₆.

2.2 Characterization

Powder X-ray diffraction (XRD) was carried out on a Shimadzu XRD-7000 X-ray diffractometer using Cu K α radiation ($\lambda = 0.15418$ nm) at a scanning rate of 2° min⁻¹ in a 2 θ range of 5°–80°. The accelerating voltage and the applied current were 40 kV and 30 mA, respectively. X-ray photoelectron spectroscopy

(XPS) was recorded on a PHI-5400 X-ray photoelectron spectrometer. Field emission scanning electron microscopy (FE-SEM) images were recorded on a JSM-6700F scanning electron microscope. High-resolution transmission electron microscopy (HRTEM) images and selected area electron diffraction (SAED) patterns were recorded on a JEM-2100 electron microscope operated at an accelerating voltage of 200 kV. UV-vis diffuse reflectance spectra (UV-vis-DRS) of the samples were obtained using a Shimadzu UV-2550 UV-vis spectrophotometer. BaSO₄ was used as a reflectance standard. Photoluminescence (PL) spectra were measured using an F-4500 spectrophotometer (Hitachi, Japan) at an excitation of 400 nm.

2.3 Photocurrent–time measurement

Photocurrent measurements were performed on an electrochemical analyzer (CHI660D, CHI Shanghai, Inc.) in a standard three-electrode configuration with a platinum wire as a counter electrode and a saturated calomel electrode (in saturated KCl) as a reference electrode. A 400 W xenon lamp with a UV cutoff filter ($\lambda > 420$ nm) is employed as the light source. Na₂SO₄ (0.1 M) aqueous solution was used as the electrolyte. The typical working electrode was prepared as follows: a 10 mg ground sample was dispersed ultrasonically in 2 mL of distilled water to make a slurry. The slurry was then dispersed onto an ITO glass electrode with an active area of about 1.0 cm², and the electrode was dried at 60 °C for 6 h. Electrochemical impedance spectra (EIS) were measured.

2.4 Photocatalytic activity

The evaluation of the photocatalytic performance of samples for photocatalytic decolorization of RhB aqueous solution was performed as follows: a 400 W halogen lamp was used as the visible-light source with a cutoff filter to cut off the light below 420 nm. A suspension containing 200 mg of photocatalyst and 200 mL of fresh aqueous solution of RhB (10 mg L⁻¹) were continuously stirred in the dark for 1.0 h to establish an adsorption/desorption equilibrium of RhB solution. After this period of time, the light source was turned on. During the reaction, 5.0 mL of samples were taken at given time intervals and the photocatalysts (Bi₂MoO₆) were then separated by centrifugation. The supernatant solution was decanted and the absorbance of RhB was determined through its maximum absorption band using a Shimadzu 2550 UV-visible spectrophotometer, and the absorption peak at 553 nm was monitored to obtain the photocatalytic degradation efficiency.⁶³

3 Results and discussion

3.1 Determination of Z-scheme CdS/Ag/Bi₂MoO₆ using XRD analysis

Fig. 1 shows XRD patterns of single-component Bi₂MoO₆ and CdS, dual CdS/Bi₂MoO₆ (120 at% C/BMO) and Ag/Bi₂MoO₆, and tri-component CdS/Ag/Bi₂MoO₆ (120 at% C/A/BMO). All the diffraction peaks can be attributed to single composite Bi₂MoO₆ (JCPDS card No. 76-2388), Ag (JCPDS card No. 04-0783) and CdS



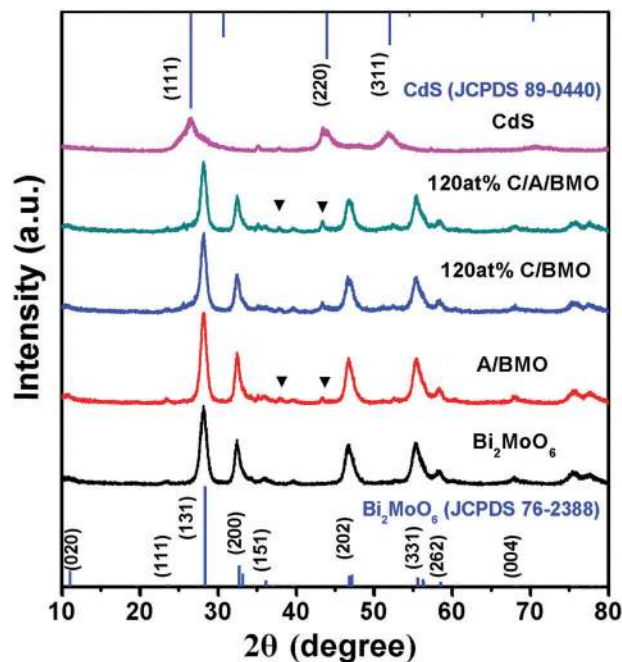


Fig. 1 XRD patterns of pure Bi_2MoO_6 and CdS, dual A/BMO and 120 at% C/BMO, and ternary 120 at% C/A/BMO composites.

(JCPDS card No. 89-0440). For samples A/BMO, C/BMO, and C/A/BMO, the characteristic diffraction peaks of BMO are still preserved. However, the XRD pattern of Ag/ Bi_2MoO_6 indicates two weak well-resolved diffraction peaks at $2\theta = 38.12^\circ$ and 44.28° , which are indexed as the (111) and (200) reflection planes of face-centered cubic Ag particles with the $Fm\bar{3}m$ space group (marked with the triangle \blacktriangledown). For the C/BMO heterostructure, diffraction peaks corresponding to the CdS phase (JCPDS card No. 89-0440) are observed, confirming the deposition of the CdS phase on BMO. For the C/A/BMO composite, after depositing CdS on the surface of A/BMO, some new diffraction peaks appear at 2θ angles of 26.46° , 43.89° and 51.98° , which can be indexed as (111), (220), and (311) reflection planes of face-centered cubic CdS crystalline particles with $F\bar{4}3d$ symmetry. The XRD patterns of the other Z-scheme C/A/BMO (80 at%, 100 at%, 140 at%, 160 at%) are similar to that of 120 at% C/A/BMO (Fig. S1, ESI †). Owing to the overlap of the diffraction peaks of the Ag and CdS phases, the positions of the diffraction peaks are slightly shifted compared to a single Ag and CdS composite. These results based on XRD analysis clearly corroborate that Z-scheme C/A/BMO composites were successfully synthesized.

3.2 Morphology and microstructure of Z-scheme C/A/BMO composite by FE-SEM and TEM analysis

The morphology and microstructure of the pure Bi_2MoO_6 and CdS, dual A/BMO, and as-prepared C/A/BMO composites are directly investigated by SEM and (HR)TEM. Bi_2MoO_6 microspheres with an average diameter of 1–2 μm are composed of a large quantity of nanoplates with thicknesses of 20–50 nm (Fig. 2a and b). The as-made CdS consists of non-uniform nanospheres, and these small nanospheres are aggregated together

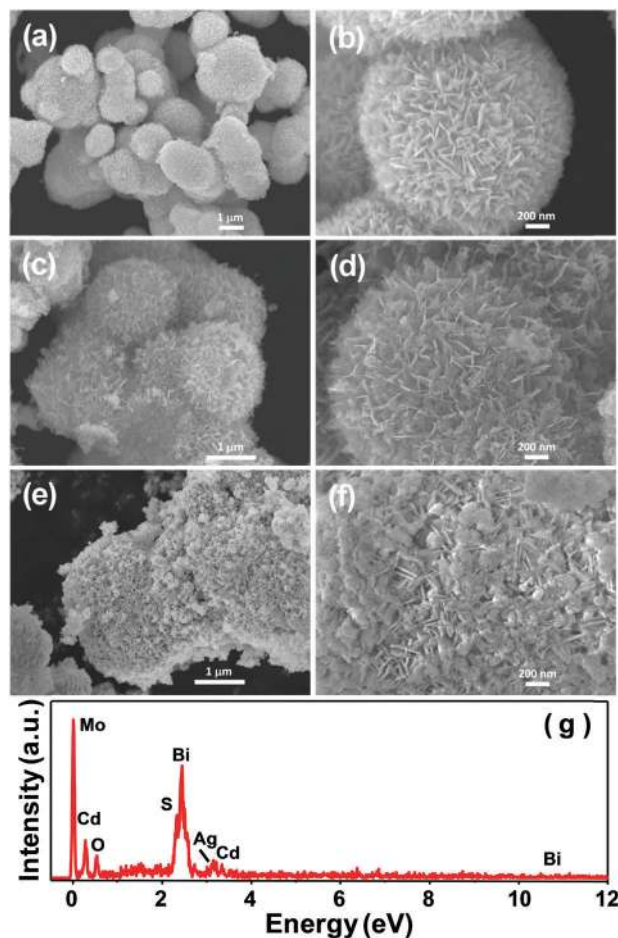


Fig. 2 FE-SEM images of (a and b) as-prepared pure Bi_2MoO_6 , (c and d) A/BMO, (e and f) 120 at% C/A/BMO composites, and (g) EDX profile of 120 at% C/A/BMO.

to form bulk clusters (Fig. S2a, ESI †). Compared with the pure Bi_2MoO_6 , the morphology of the Ag/ Bi_2MoO_6 composite is quite similar to that of precursor Bi_2MoO_6 in a large area (Fig. 2c and d), but some small spherical Ag particles loaded onto the surface of the Bi_2MoO_6 architectures are observed, indicating that Ag nanoparticles were successfully prepared and highly dispersed on the surface of the Bi_2MoO_6 nanoarchitectures, which is consistent with the XRD results. For the as-made C/A/BMO composite, the SEM images clearly indicate that many irregularly spherical CdS particles deposited on the surface of A/BMO achieved partial or complete coverage of A/BMO, showing the formation of obvious agglomerations (Fig. 2e and f). To further identify the presence of CdS and Ag on the surface of Bi_2MoO_6 microspheres, microanalysis of the C/A/BMO composite was performed by energy dispersive X-ray (EDX) spectroscopy. The EDX spectrum from Fig. 2f is shown in Fig. 2g, confirming that the composite contained the elements Ag, Bi, Mo, O, Cd, and S.

To further identify the microstructure of the as-synthesized C/A/BMO composite, transmission electron microscopy (TEM) was performed and representative TEM images are shown in Fig. 3. For the pure Bi_2MoO_6 , a flower-like microsphere structure is observed (Fig. 3a). Single-component CdS is composed of



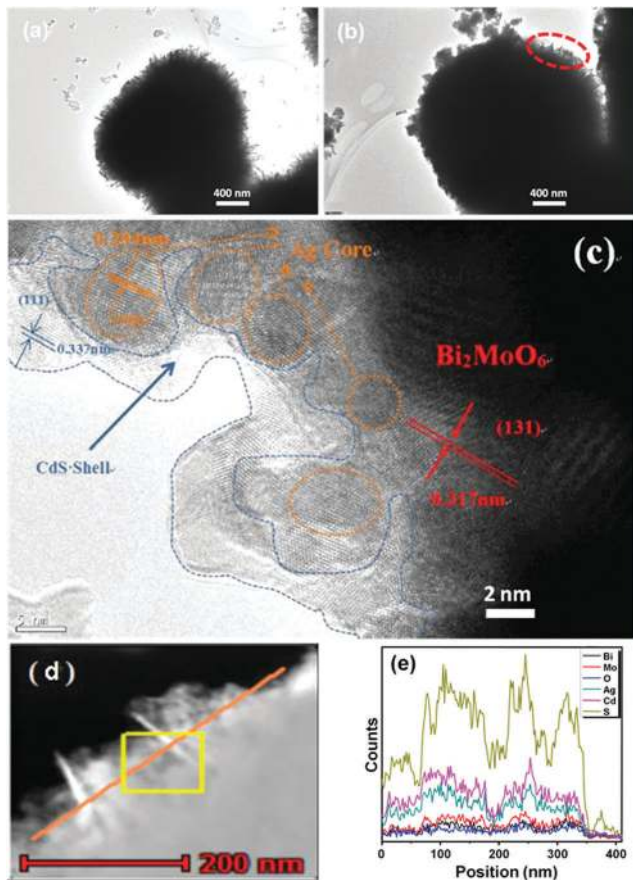


Fig. 3 TEM image of (a) Bi_2MoO_6 , (b) C/A/BMO, (c) HRTEM image of C/A/BMO, (d) HAADF-STEM image of C/A/BMO composite, and (e) EDX line-scanning elemental mappings of a single C/A/BMO particle (indicated by red line in (b)).

irregular nanoparticles with a size of about 10 nm (Fig. S2b, ESI[†]). For the Z-scheme photocatalytic system C/A/BMO, representative (HR)TEM images are presented in Fig. 3b and c. The measured lattice fringes of the (131) plane of Bi_2MoO_6 with a d -spacing of 0.317 nm, of the (200) plane of Ag with a d -spacing of 0.204 nm, and of the (111) plane of CdS with a d -spacing of 0.337 nm, are in good agreement with those calculated from the wide angle PXRD data, further demonstrating the presence of face-centered cubic Ag and CdS phases in the Bi_2MoO_6 composite. Moreover, for the 120 at% C/A/BMO nanocomposite, the high-angle annular dark field scanning transmission electron microscopy (HAADF-STEM) image in Fig. 3d and the spatial distribution of the elemental composition along the edges of the particles in Fig. 3e, investigated by line-scanning elemental mappings, clearly corroborated a well-defined compositional profile of the C/A/BMO nanostructures. The profiles of Bi, Mo, and O show a narrow band-like peak at the center, whereas the profiles of Ag, S, and Cd show slightly sharp peaks at the right and left sides with a broad valley in the center, showing a clear interface between the CdS and Bi_2MoO_6 components of the heterostructures.

3.3 XPS analysis

XPS spectra of the samples are performed to investigate the surface valence state and the chemical composition. As shown

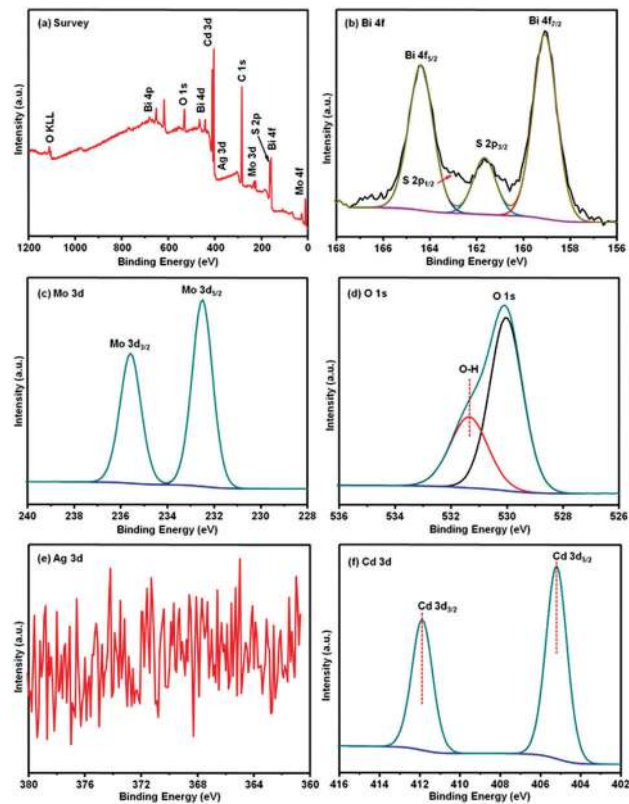


Fig. 4 XPS spectra of sample 120 at% C/A/BMO: (a) the survey spectrum, (b) Bi 4f and S 2p, (c) Mo 3d, (d) O 1s, (e) Ag 3d, and (f) Cd 3d.

in Fig. 4a, the XPS survey spectra are mainly composed of Bi, Mo, O, Ag, S, and Cd elements, which are consistent with the chemical composition of the photocatalysts. The C element came from the adventitious hydrocarbon of the XPS instrument itself. High-resolution spectra of Bi 4f, Mo 3d, O 1s, Ag 3d, and Cd 3d of sample 120 at% C/A/BMO are shown in Fig. 4b–f, respectively. As viewed in Fig. 4b, two strong peaks at around 158.5 and 163.7 eV are observed, which can be assigned to the binding energies of Bi 4f_{7/2} and Bi 4f_{5/2}, respectively.⁶⁴ Two bands at 232.2 and 235.3 eV in Fig. 4c are ascribed to Mo 3d_{5/2} and Mo 3d_{3/2}, respectively.⁶⁵ The observed two O 1s peaks at 531.2 and 529.9 eV in Fig. 4d are in agreement with OH hydroxyl groups and oxygen species in the lattice oxygen, respectively.⁶⁶ Moreover, the monitored Ag 3d spectrum is very weak, due to a very low loading of Ag (Fig. 4e). However, the XPS spectrum of Cd 3d clearly indicates two characteristic bands at 404.9 and 412.3 eV, which can be assigned to the Cd²⁺ ions in CdS.⁶⁷ Furthermore, the S element can also be detected in the XPS spectrum in Fig. 4b at around 160.5 and 159.5 eV, revealing binding energies of characteristic S 2p_{3/2} and S 2p_{1/2}, respectively.^{68,69} As a comparison, the high-resolution XPS spectra of Cd 3d of pristine CdS, Bi 4f of pristine Bi_2MoO_6 , and 120 at% C/A/BMO are shown in Fig. S3 (ESI[†]). The binding energies of Bi 4f_{5/2} and Bi 4f_{7/2} of Bi_2MoO_6 are lower (0.2 eV) than those of the 120 at% C/A/BMO (Fig. S3a, ESI[†]). Note that the binding energy of the Cd 3d_{3/2} and Cd 3d_{5/2} from pure CdS is higher (0.25 eV) than those from the 120 at% C/A/BMO



(Fig. S3b, ESI[†]). These results imply that the deposited CdS nanoparticles are probably attached on the surface of BMO, not *via* a simply physical mixture.⁷⁰ Based on these XPS results, Ag and CdS have been successfully loaded on the surface of Bi₂MoO₆ to fabricate a Z-scheme C/A/BMO photocatalytic system, which has been confirmed by HRTEM and EDX measurement.

3.4 FT-IR spectra analysis

To investigate the chemical composition and characteristic chemical bonding of the composites, Fourier transform infrared spectroscopy (FT-IR) was carried out. Fig. 5a shows the FT-IR spectra of the as-prepared pure Bi₂MoO₆, A/BMO, 120 at% C/BMO, 120 at% C/A/BMO, and pure CdS. For pure Bi₂MoO₆, the characteristic Mo–O asymmetric and symmetric stretching vibrations of MoO₆ octahedra, involving vibration of the apical oxygen atoms, appear at 843 and 797 cm⁻¹, respectively.^{71–73} Moreover, the bands at 734 cm⁻¹, attributed to the Mo–O asymmetric stretching mode, involving vibrations of the equatorial oxygen atoms from MoO₆, and at 603 and 570 cm⁻¹, assigned to the bending vibration of MoO₆, as well as at 455 cm⁻¹, belonged to the Bi–O stretching and bending vibrations from the BiO₆ unit, are observed as in a previous study reported by Zhu and co-workers.⁷³ For single-component CdS, the characteristic Cd–S bond appears at 1384 and 1118 cm⁻¹.⁷⁴ Owing to surface adsorption of water on CdS, the O–H bending vibration appears at 1630 cm⁻¹.²⁶ It is worth noting that an absorption peak appears at about 1045 cm⁻¹ for A/BMO and 120 at% C/A/BMO, which can be attributed to the resonance absorption of Ag nanoparticles. For Ag/Bi₂MoO₆, C/BMO, and C/A/BMO, the corresponding characteristic chemical bonding vibrations (Mo–O, Cd–S and Bi–O) appear in their IR spectra, clearly verifying the successful synthesis of the corresponding composites. These results are in good agreement with data from the XRD, SEM and (HR)TEM analyses.

3.5 UV-vis-DRS analysis

Typical UV-vis diffuse reflectance spectroscopy (UV-vis-DRS) is a useful method to reflect the optical absorption properties of the as-prepared samples. As viewed in Fig. 5b and Fig. S4 (ESI[†]), the absorption edge of pure Bi₂MoO₆ is estimated to be 470 nm, while pure CdS shows a strong absorption at 556 nm in the UV range. The multicomposites, A/BMO, 120 at% C/BMO, 120 at% C/A/BMO, and other Z-scheme C/A/BMO (80 at%, 100 at%,

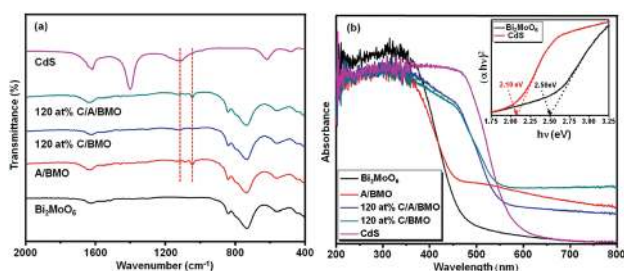


Fig. 5 (a) FT-IR spectra and (b) UV-vis DRS spectra of pure Bi₂MoO₆ and CdS, dual A/BMO and 120 at% C/BMO, and Z-scheme ternary 120 at% C/A/BMO composites. The inset is the plot of absorption $(\alpha h\nu)^2$ versus energy $(h\nu)$ for the band gap energy of pure Bi₂MoO₆ and CdS.

140 at% and 160 at%), respectively exhibit a strong absorption ability in the range of 400–800 nm, compared to pure Bi₂MoO₆, indicating that the loading of Ag and CdS can effectively enhance the visible-light absorption. For A/BMO, it is noteworthy that an extra absorption peak in the visible-light absorption region (about 540 nm) is found and can be ascribed to the surface plasmon resonance (SPR) absorption of the Ag nanoparticles.^{59,60} However, for the C/A/BMO composite, the SPR absorption significantly broadens and a red-shift of the Ag surface plasmon band of about 100 nm occurs, compared with A/BMO, suggesting a strong electronic interaction between Ag and CdS.^{43,75} Therefore, this phenomenon confirms that the Ag nanoparticles deposited on Bi₂MoO₆ are coated by CdS.

The band gap energies (E_g) of the semiconductors are calculated from a plot of $(\alpha h\nu)^{2/n}$ versus energy $(h\nu)$ (Fig. 5b, inset), according to the equation of the optical absorption near a band edge: $\alpha h\nu = A(h\nu - E_g)^{n/2}$,⁷⁶ where α , $h\nu$, E_g , and A are the optical absorption coefficient, photonic energy, photonic energy band gap, and proportionality constant, respectively. In this equation, n depends on whether the transition is direct ($n = 1$) or indirect ($n = 4$). As shown in the literature, Bi₂MoO₆ and CdS are direct optical transition-type semiconductors.^{77,78} The direct band gaps of pure Bi₂MoO₆ and CdS can be obtained from the chart of absorption $(\alpha h\nu)^2$ versus energy $h\nu$ (Fig. 5b, inset). Thus, the band gaps of pure Bi₂MoO₆ and CdS are determined to be 2.10 and 2.50 eV, respectively.

3.6 Photocatalytic activity

Photocatalytic decomposition of RhB on various samples as photocatalysts is evaluated under visible light irradiation ($\lambda > 420$ nm). Fig. 6a presents the photocatalytic degradation results of RhB over single component CdS, pure Bi₂MoO₆, A/BMO,

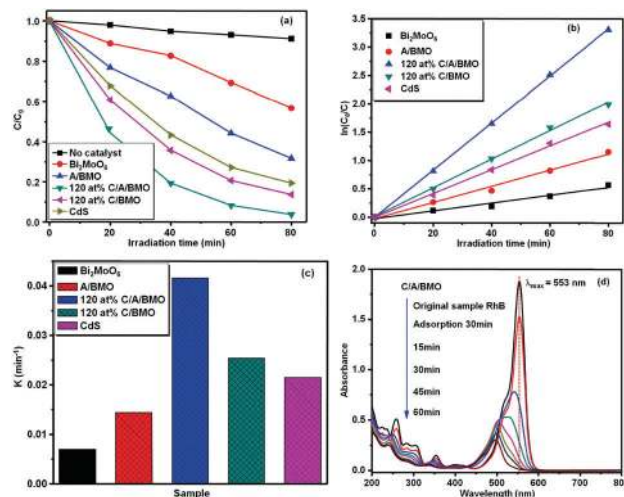


Fig. 6 (a) Photocatalytic degradation efficiency of RhB by pure Bi₂MoO₆, A/BMO, 120 at% C/BMO, 120 at% C/A/BMO composites and single CdS, (b) kinetic plot of C/C_0 versus irradiation time for the photodegradation of RhB using different photocatalysts, (c) rate constants of the photodegradation of RhB using different photocatalysts, and (d) the change in the absorption spectra of photodegraded RhB with increasing irradiation time under visible light, using 120 at% C/A/BMO composite as a photocatalyst.



120 at% C/BMO, and 120 at% C/A/BMO composites. The results indicate that the photocatalytic degradation efficiency of RhB was approximately 40%, using pure Bi_2MoO_6 as a photocatalyst after irradiation for 80 min. The low yield is probably caused by the rapid recombination of photogenerated electrons and holes of the Bi_2MoO_6 microspheres. As compared to the pure Bi_2MoO_6 , both A/BMO and C/BMO as catalysts significantly improve the photocatalytic activity, proving that Ag nanoparticles and CdS played an important role in enhancing the photocatalytic performance. It is interesting to note that the 120 at% C/A/BMO as a photocatalyst displays the highest photocatalytic degradation efficiency compared to pure Bi_2MoO_6 , A/BMO, and C/BMO. The highly photocatalytic performance is attributed to the positive synergy of Ag and CdS on the surface of Bi_2MoO_6 . Hence, for the photodegradation of RhB, the photocatalytic activity of all the catalysts used is as follows in order from slow to fast: $\text{Bi}_2\text{MoO}_6 < \text{A/BMO} < \text{CdS} < 120 \text{ at\% C/BMO} < 120 \text{ at\% C/A/BMO}$. In addition, the screening of all the Z-scheme C/A/BMO photocatalysts with different amounts of CdS for enhanced photocatalytic activities is shown in Fig. S5 (ESI[†]), clearly revealing that 120 at% C/A/BMO is the best photocatalyst. Furthermore, in order to better compare the photocatalytic efficiency of all the samples, the reaction kinetics of RhB degradation were investigated. According to the Langmuir-Hinshelwood (L-H) kinetics model,^{79,80} the pseudo first-order kinetics equation is expressed as $\ln(C_0/C) = k_{\text{app}} \cdot t$, where k_{app} denotes the apparent rate constant (min^{-1}), C_0 and C are the RhB concentrations (mg L^{-1}) in solution at time $t = 0$ and $t = t$, and t represents the irradiation time (min). With increasing irradiation time, the plot of $\ln(C_0/C)$ versus irradiation time (t) for RhB degradation over different photocatalysts is shown in Fig. 6b. The results reveal that the photodegradation of RhB is a typical pseudo first-order reaction in the presence of the photocatalysts (Bi_2MoO_6 , A/BMO, C/BMO, and C/A/BMO). The corresponding rate constants (k_{app}) of the photodegradation of RhB are shown in Fig. 6c, these are 6.92×10^{-3} , 1.43×10^{-2} , 2.146×10^{-2} , 2.534×10^{-2} , and $4.155 \times 10^{-2} \text{ min}^{-1}$ for pure Bi_2MoO_6 , A/BMO, single-phase CdS, 120 at% C/BMO, and 120 at% C/A/BMO, respectively. These findings clearly confirm that the C/A/BMO composite is the most active photocatalyst for the photocatalytic degradation of RhB; its activity is approximately 6 times higher than that of pure Bi_2MoO_6 .

The temporal evolution of the absorption spectra of photo-degraded RhB with increasing irradiation time are illustrated in Fig. 6d in the presence of the 120 at% C/A/BMO composite catalyst. At the beginning of photodegradation, the strongest absorbance of RhB locates at 554 nm, and with increasing irradiation time, the absorption peak gradually decreases and undergoes a blue-shift to 498 nm after 80 min irradiation. The blue-shift is caused by the *N*-deethylation and deethylation of RhB during irradiation.⁸¹

3.7 Photoluminescence analysis

Owing to the photoluminescence (PL) emission originating from the recombination of free charge carriers, PL spectra are often used to investigate the efficiency of separation and transfer of photogenerated charge carriers, and the fate of photogenerated

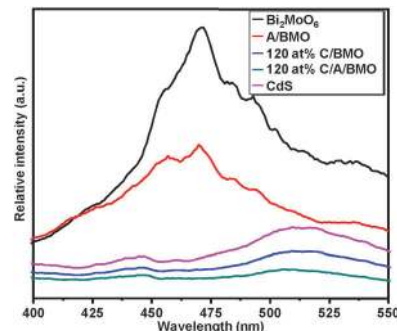


Fig. 7 PL spectra of pure Bi_2MoO_6 and CdS, A/BMO, 120 at% C/BMO, and 120 at% C/A/BMO composite.

electrons and holes in semiconductors.^{69,71,82} It is well known that a lower PL intensity indicates a lower recombination rate of photogenerated electron-hole pairs and thereby shows high photocatalytic activity.⁶⁴ Hence, we measured the PL emission spectra of pure Bi_2MoO_6 , Ag/ Bi_2MoO_6 , C/BMO (120 at%), the C/A/BMO (120 at%) composite, and single CdS, as shown in Fig. 7. For the pure Bi_2MoO_6 , one characteristic emission peak centred at about 460 nm is observed, which is in accordance with previously reported results.^{71,83} After introducing Ag nanoparticles and CdS onto the surface of Bi_2MoO_6 , the intensity of the PL emission of the C/A/BMO composites is obviously lower than that of other samples, implying that the incorporation of Ag and CdS nanoparticles on the BMO composite can effectively repress the recombination of electron-hole pairs and thereby generate a higher photocatalytic activity, which is in good agreement with the result from the RhB photodegradation experiment.

3.8 Photoelectrochemical properties

Photocurrent measurements are usually utilized to investigate interfacial charge transfer dynamics. A high photocurrent implies a high separation efficiency of electrons and holes, showing a high photocatalytic activity.⁸⁴ Fig. 8 displays the transient photocurrent responses of pure Bi_2MoO_6 , 120 at% C/BMO, 120 at% C/A/BMO, and single CdS, with several on-off

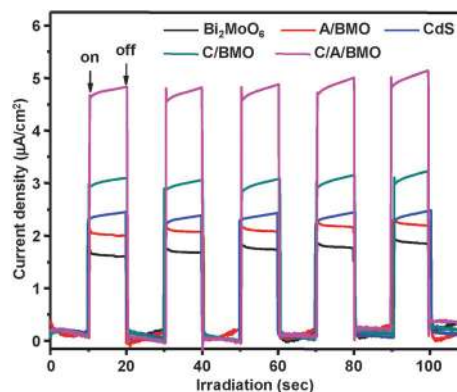


Fig. 8 Comparison of transient photocurrent responses of pure Bi_2MoO_6 and CdS, A/BMO, 120 at% C/BMO, and 120 at% C/A/BMO composite under visible light irradiation ($\lambda > 420 \text{ nm}$, $[\text{Na}_2\text{SO}_4] = 0.1 \text{ M}$).



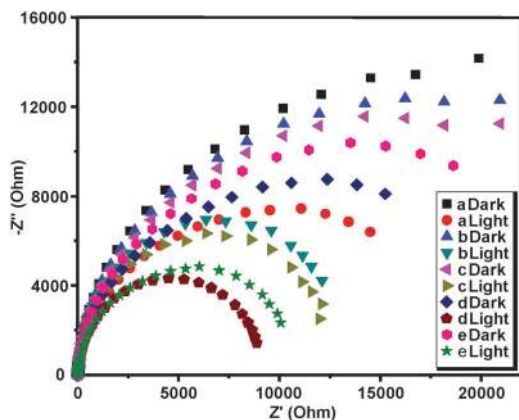


Fig. 9 Electrochemical impedance Nyquist plots of samples (a) pure Bi_2MoO_6 , (b) A/BMO, (c) CdS, (d) 120 at% C/A/BMO, and (e) 120 at% C/BMO electrodes under dark and light irradiation in the 0.5 M Na_2SO_4 electrolyte.

cycles of visible light illumination. In comparison with pure Bi_2MoO_6 and single CdS, C/A/BMO exhibits a significantly enhanced transient photocurrent density, which is about 3 times and 2 times higher than that of the pure Bi_2MoO_6 and single CdS, respectively. The results reveal that C/A/BMO possesses a higher separation efficiency of photogenerated electrons and holes, further confirming that the synergy of Ag and CdS on the surface of Bi_2MoO_6 is far superior to that of pure Bi_2MoO_6 , the CdS/ Bi_2MoO_6 composite, and single CdS.

Moreover, the migration and transfer processes of photo-generated electrons and holes in a semiconductor can also be verified by a typical electrochemical impedance spectrum (EIS).⁸⁵ The radius of the arc in the EIS reflects the interface layer resistance occurring on the surface of the electrode. Previous studies revealed that a smaller arc radius implied a higher efficiency of charge transfer.^{86–88} As shown in Fig. 9, typical EIS Nyquist plots of the pure Bi_2MoO_6 , A/BMO, 120 at% C/BMO, 120 at% C/A/BMO, and single CdS, before and after visible light irradiation, clearly show that the arc radii for A/BMO and C/BMO are smaller than those for pure Bi_2MoO_6 and CdS under light or dark conditions, but are larger than that of the C/A/BMO composite, implying that C/A/BMO (120 at%) possesses a stronger ability to separate and transfer photo-generated electron-hole pairs. This result indicates that the incorporation of Ag and CdS on the surface of Bi_2MoO_6 can effectively enhance the separation and transfer of photogenerated electron-hole pairs and thereby leads to an improvement in photocatalytic degradation efficiency. The results of the EIS are in accordance with the aforementioned PL and photocurrent experiments. Subsequently, the photocurrent generation and EIS experiments better demonstrate the electron excitation and the charge transport characteristics of 120 at% C/A/BMO samples.

3.9 Photocatalytic mechanism

During the photodegradation of organic pollutants, the active species, including superoxide anion radicals ($\bullet\text{O}_2^-$), positive holes (h^+), and hydroxyl radicals ($\bullet\text{OH}$), play a crucial role.

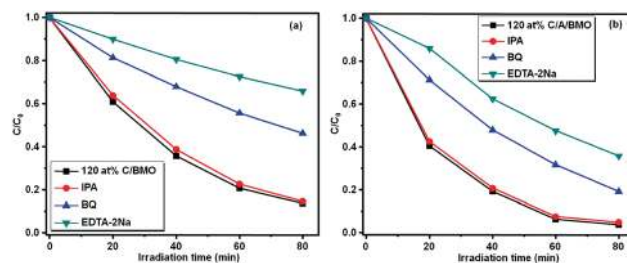


Fig. 10 Trapping experiments of active species for RhB photodegradation in the presence of photocatalyst (a) 120 at% C/BMO, (b) 120 at% C/A/BMO under visible light irradiation.

To further reveal the possible mechanism of the enhanced photocatalytic performance, a trapping experiment for identifying the main active species was performed. Sacrificial agents, such as disodium ethylene diamine-tetraacetate (EDTA-2Na), isopropanol (IPA), and benzoquinone (BQ), are utilized as scavengers of h^+ , $\bullet\text{OH}$, and $\bullet\text{O}_2^-$, respectively.^{89,90} The trapping experiments of active species for the photocatalytic reactions of the samples shown in Fig. 10 indicate that IPA barely affects the photocatalytic efficiency, while the photocatalytic activity of the samples are obviously inhibited by the addition of EDTA-2Na and BQ. This fact demonstrates that superoxide anion radicals $\bullet\text{O}_2^-$ and positive holes h^+ are the main active species and play key roles in the RhB photodegradation process, compared with the hydroxyl radical $\bullet\text{OH}$ in the presence of composites 120 at% C/BMO or 120 at% C/A/BMO under visible light irradiation. Nevertheless, the addition of EDTA-2Na quickly represses the RhB degradation compared to that with the addition of BQ, revealing that positive holes h^+ play a more important role than hydroxyl radicals $\bullet\text{O}_2^-$ in the photocatalytic reactions.

To further confirm the formation of the Z-scheme C/A/BMO, the energy band levels of Bi_2MoO_6 and CdS are determined. As shown in Fig. 11a, the band gaps of Bi_2MoO_6 and CdS are 2.5 and 2.16 eV, respectively. The calculated VB positions of Bi_2MoO_6 and CdS are approximately 2.29 and 1.7 eV, respectively, via the equation $E_{\text{CB}} = \chi - E^e - E_{\text{g}}$, and their corresponding CB edge levels (E_{CB} vs. NHE) are calculated to be -0.21 and -0.46 eV, respectively, via the equation $E_{\text{VB}} = E_{\text{g}} + E_{\text{CB}}$, where E_{CB} is the CB edge potential, E_{VB} is the VB edge

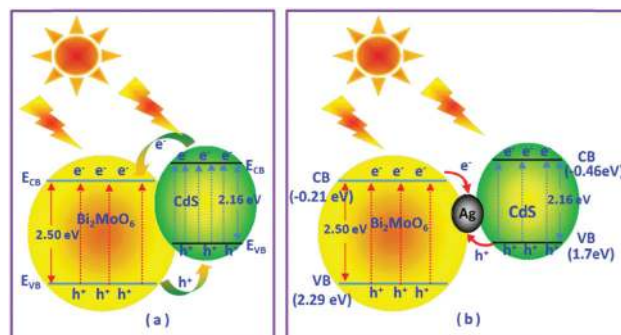
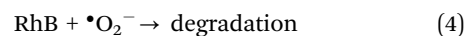
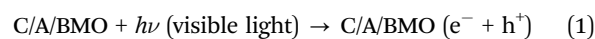


Fig. 11 Schematic illustration of the charge transfer in samples (a) C/BMO and (b) C/A/BMO under visible light irradiation.



potential, and χ is the electronegativity of the semiconductor. E^e is the energy of free electrons on the hydrogen scale ≈ 4.5 eV and E_g is the band gap of the semiconductor.^{70,91} Based on the energy band levels of Bi_2MoO_6 and CdS, and the above-mentioned trapping experiments of active species, herein, we suggest that the photogenerated charge migration in the C/BMO composite is similar to the typical charge migration mechanism of a semiconductor heterojunction (Fig. 11a). When Bi_2MoO_6 and CdS are excited by visible light irradiation, the photogenerated electrons on the CB of CdS can easily migrate to the CB of Bi_2MoO_6 , while the photogenerated holes in the VB of Bi_2MoO_6 can transfer to the VB of CdS. As a result, the photogenerated electrons and holes are spatially separated and undesirable recombination is greatly weakened. But in the CdS– Bi_2MoO_6 system, as the top of the valence band potential of CdS is less positive than that of Bi_2MoO_6 and the bottom of the conduction band potential of Bi_2MoO_6 is less negative than that of CdS, it is difficult to simultaneously possess high charge-separation efficiency and strong redox ability, resulting in a weak redox ability, especially after charge transfer. As shown in Fig. 11a, the hole density in the VB of Bi_2MoO_6 is depleted, while the hole density in the VB of CdS is enhanced during the photocatalytic process, hence, the redox ability of the transferred electrons and holes is reduced,^{42,92} showing a negative effect on the photocatalytic reactions. Note that the catalytic performance of this type of photocatalyst is much higher than that of a single semiconductor and single-component catalyst. As a result, for the RhB photodegradation, the catalytic performance shown in Fig. 6a clearly reveals that the heterojunction-type C/BMO catalyst displays a higher photocatalytic behavior than single semiconductor CdS and single Bi_2MoO_6 due to effective separation of the photogenerated electrons and holes. For the C/A/BMO photocatalytic system, a different mechanism is suggested, as shown in Fig. 11b. Although the spatial separation of photogenerated electrons and holes in Z-scheme C/A/BMO is similar to that in the heterojunction-type catalyst, C/BMO, under light irradiation, the photogenerated electrons from the CB of Bi_2MoO_6 can readily recombine with the photogenerated holes from the VB of CdS by ohmic contact with Ag NPs as conductor, because on the one hand, equilibrium of the Fermi levels is established at the solid–solid interfaces of Bi_2MoO_6 , Ag and CdS before light irradiation. On the other hand, the strong SPR effect of Ag nanoparticles results in an enhanced local electric field around the solid–solid interfaces, which can drive the excited electrons of Ag to inject into the VB of CdS to recombine with holes or into the CB of CdS *via* direct electron transfer or plasmon-induced resonant energy transfer.^{20,93} As a result, the photogenerated electrons in the VB of CdS continuously transit to the CB of CdS under light irradiation, and the photogenerated electrons aggregate in the CB of CdS to form an electron-rich region, and thereby suppress the photo-oxidation of CdS, while the photogenerated holes aggregate in the VB of Bi_2MoO_6 to make a hole-rich region and therefore protect Bi_2MoO_6 from photo-reduction. Hence, the electron-rich region and the hole-rich region readily allow strong photo-reduction and

photo-oxidation, respectively, indicating a high photocatalytic performance with spontaneous and circular photo-reduction and photo-oxidation. Moreover, the photogenerated electrons from the CB of Bi_2MoO_6 can directly recombine with the photogenerated holes from the VB of CdS through ohmic contact with Ag nanoparticles, which greatly reduces the distance of Z-scheme electron transfer. This further improves the efficient separation of electrons from the CB of CdS and holes from the VB of Bi_2MoO_6 . This is why Z-scheme catalyst C/A/BMO exhibits the highest photocatalytic performance in RhB photodegradation compared to C/BMO (Fig. 6a). Contrarily, addition of EDTA-2Na or BQ more rapidly represses the rate of RhB photodegradation in the presence of CdS/Ag/ Bi_2MoO_6 compared to that in the presence of CdS/ Bi_2MoO_6 (Fig. 10). It is noteworthy that the Z-scheme charge transfer pathway not only greatly improves the separation of electron–hole pairs, but also preserves strong and continuous redox ability. According to the above-mentioned discussion, the Z-scheme CdS/Ag/ Bi_2MoO_6 -catalyzed RhB photodegradation can be proposed as follows:



4 Conclusions

In summary, a novel Z-scheme photocatalytic system, CdS/Ag/ Bi_2MoO_6 (C/A/BMO), was rationally designed and successfully prepared. As a comparison, a series of single-component CdS and Bi_2MoO_6 , and dual-component CdS/ Bi_2MoO_6 (C/BMO) and Ag/ Bi_2MoO_6 (A/BMO) were also synthesized. All composites were characterized by XRD, SEM, TEM, XPS, EDX, IR, and UV visible spectra to confirm their phase composition, morphology and structure. The results revealed that Ag and CdS were successfully integrated to the surface of Bi_2MoO_6 to form Ag– Bi_2MoO_6 (A/BMO) and CdS– Bi_2MoO_6 (C/BMO), as well as CdS–Ag solid–solid contact interfaces in different composite materials, Ag/ Bi_2MoO_6 (A/BMO), CdS/ Bi_2MoO_6 (C//BMO), and CdS/Ag/ Bi_2MoO_6 (C/A/BMO). All the materials can be used as photocatalysts for the degradation of RhB dye under visible light irradiation. Owing to the high electronic mobility and strong SPR effect of Ag nanoparticles, the introduction of Ag NPs provides a high-speed charge transfer channel in the CdS/Ag/ Bi_2MoO_6 (C/A/BMO) heterostructure and thereby leads to more efficient spatial separation of the electrons and holes. Moreover, the photodegradation of RhB dye under visible light irradiation revealed that the multicomposite CdS–Ag– Bi_2MoO_6 (C/A/BMO) photocatalytic system exhibited the most efficient photocatalytic activity compared to single CdS and Bi_2MoO_6 , and dual Ag/ Bi_2MoO_6 (A/BMO) and CdS/ Bi_2MoO_6 (C/BMO), showing highly efficient separation of the photogenerated electrons and holes, and stable and strong reducibility and oxidizability in the Z-scheme photocatalytic system, CdS–Ag– Bi_2MoO_6



(C/A/BMO). Hence, the highly efficient photocatalytic performance of CdS–Ag–Bi₂MoO₆ (C/A/BMO) can be explained by a Z-scheme charge-transfer mechanism. Furthermore, the photoluminescence properties and photoelectrochemical properties of single CdS and Bi₂MoO₆, dual Ag/Bi₂MoO₆ (A/BMO) and CdS/Bi₂MoO₆ (C/BMO), and tri-composite CdS/Ag/Bi₂MoO₆ (C/A/BMO) were also investigated in detail, indirectly corroborating the highly photocatalytic performance of Z-scheme catalyst, CdS/Ag/Bi₂MoO₆ (C/A/BMO).

Acknowledgements

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